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September 5, 2000

*By certified mail  
Return receipt requested*

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**Mr. Mark Durcan**  
**Micron Technology, Inc.**  
**8000 S. Federal Way, MS 840**  
**Boise, Idaho 83716-9632**

**RE: Invention Disclosures (ASU Case Nos)**

<b>M1-006</b>	“Solid Solution for the Programmable Metallization Cell”
<b>M1-007</b>	“Optimized Electrodes for the Programmable Metallization Cell”
<b>M1-008</b>	“Programmable Metallization Cell With Floating Electrode”
<b>M1-009</b>	Method for the Synthesis of Macrohomogeneous Germanium Chalcogenide Glasses”
<b>M1-010</b>	“Common Electrode Configurations for the Programmable Metallization Cell”
<b>M1-011</b>	“Ultra Low Energy Programmable Metallization Cell Devices”

Dear Mark,

I have received notification from ASU of the above-referenced invention disclosures. In the opinion of ASU, all the disclosures represent “IMPROVEMENT INVENTIONS” as defined in the Research Agreement between Axon and ASU. I have therefore instructed our patent counsel to prepare, file, prosecute and maintain patents on these disclosures.

This letter is written in compliance of with Paragraph 3.2 of the Research and License Agreement dated March 22, 2000 between Micron Technology, Inc. and Axon Technologies Corporation. The text of each of the referenced disclosures is included with this letter.

Sincerely,

Vic Lyn  
Executive Vice President

Cc: Roderic Lewis, General Counsel, Micron Technology, Inc.  
Michael Kozicki, ASU  
Quinn Williams, Snell & Wilmer  
Cindy Pillote, Snell & Wilmer

Enclosures